


Features:

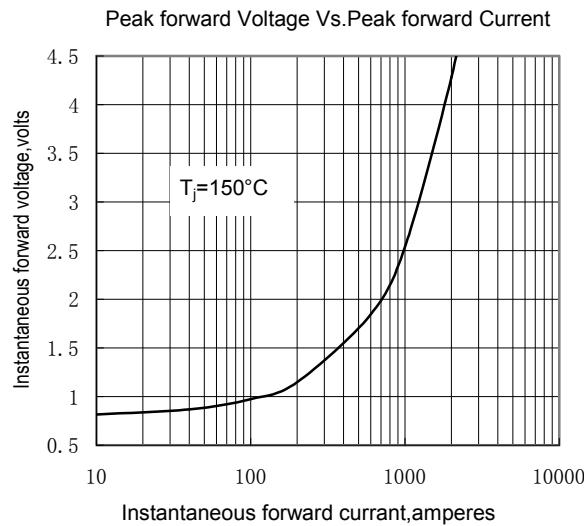
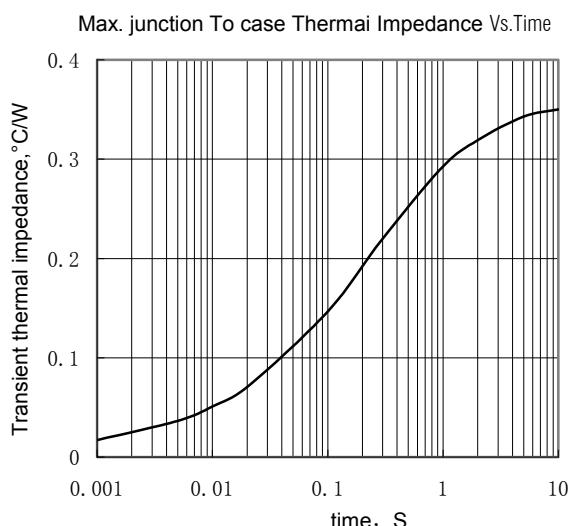
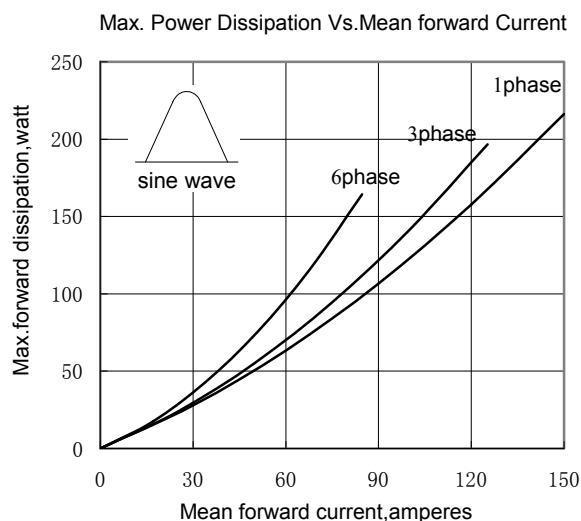
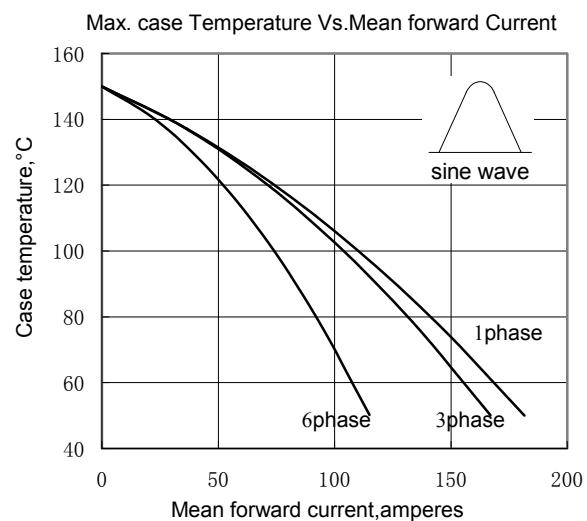
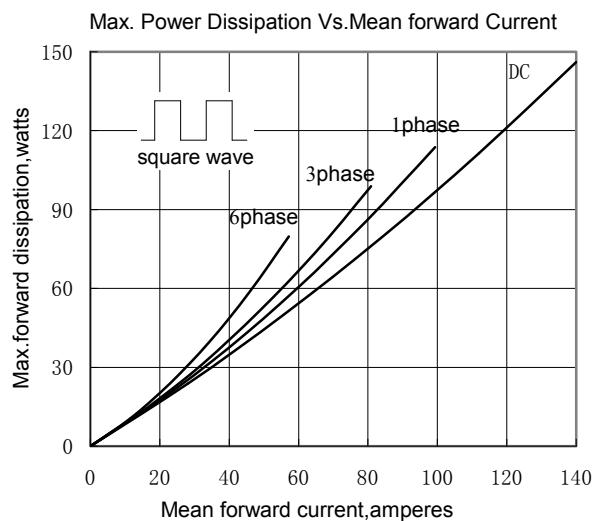
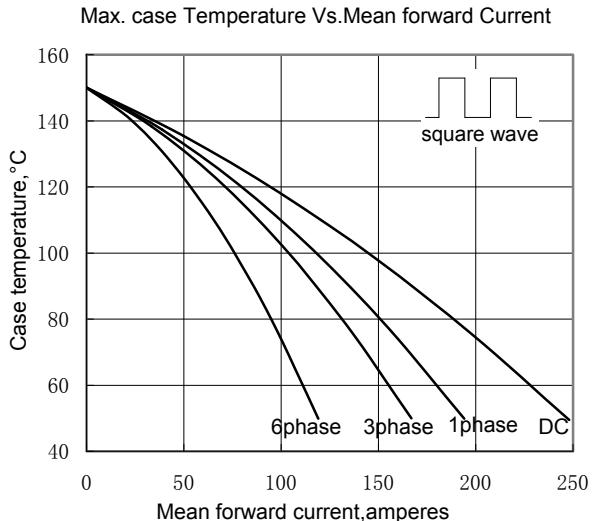
- High performance thermal insulation materials
- Good thermal fatigue performance
- International standard package

Typical Applications

- Various rectifiers
- DC supply for PWM inverter

V_{RSM}	V_{RRM}	Type & Outline
900V	800V	MDx100-08
1100V	1000V	MDx100-10
1300V	1200V	MDx100-12
1500V	1400V	MDx100-14
1700V	1600V	MDx100-16
1900V	1800V	MDx100-18

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_j(^{\circ}\text{C})$	VALUE			UNIT
				Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz Single side cooled, $T_c=100^{\circ}\text{C}$	150			100	A
$I_{F(RMS)}$	RMS forward current		150			157	A
I_{RRM}	Repetitive peak current	at V_{RRM}	150			10	mA
I_{FSM}	Surge forward current	10ms half sine wave	150			2.60	KA
I^2t	I^2t for fusing coordination	$V_R=0.6V_{RRM}$				34	$\text{A}^2\text{s} \times 10^3$
V_{FO}	Threshold voltage		150			0.80	V
r_F	Forward slop resistance					1.74	$\text{m}\Omega$
V_{FM}	Peak forward voltage	$I_{FM}=300\text{A}$	25			1.45	V
$R_{th(j-c)}$	Thermal resistance Junction to case	At 180° sine Single side cooled per chip				0.350	$^{\circ}\text{C}/\text{W}$
$R_{th(c-h)}$	Thermal resistance case to heatsink	At 180° sine Single side cooled per chip				0.2	$^{\circ}\text{C}/\text{W}$
V_{iso}	Isolation voltage	50Hz,R.M.S,t=1min, $I_{iso}=1\text{mA}(\text{max})$		2500			V
F_m	Terminal connection torque(M5)				4		$\text{N}\cdot\text{m}$
	Mounting torque(M6)				6		$\text{N}\cdot\text{m}$
T_{stg}	Stored temperature			-40		125	$^{\circ}\text{C}$
W_t	Weight				105		g
Outline				M01H			


Fig.1

Fig.2

Fig.3

Fig.4

Fig.5

Fig.6

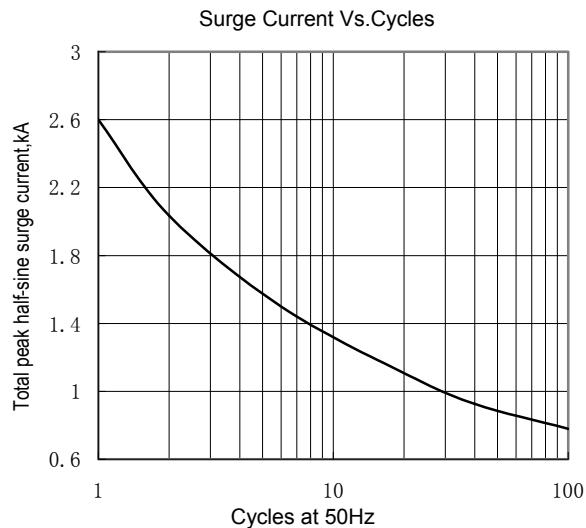


Fig.7

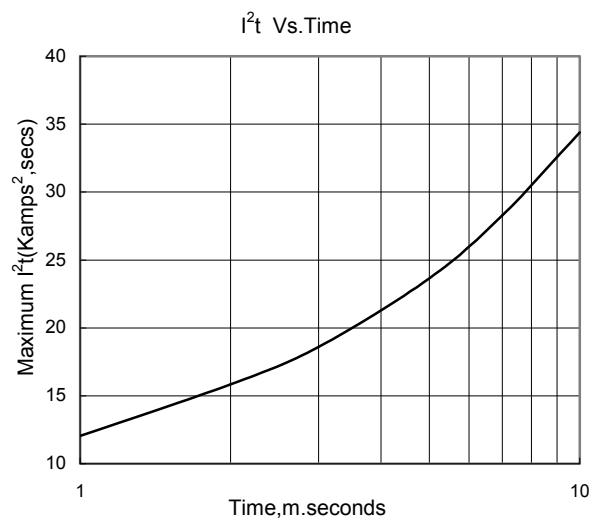
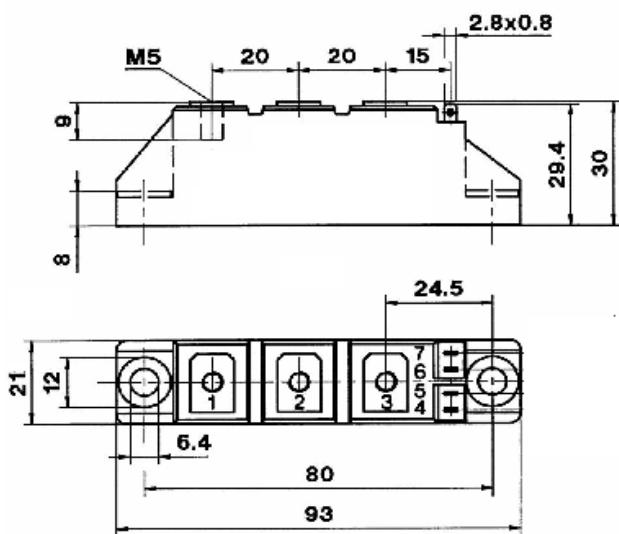


Fig.8

Outline:



M01H

